



STBV45

HIGH VOLTAGE FAST-SWITCHING NPN POWER TRANSISTOR

Table 1: Order Codes

| Ordering Code | Marking | Package / Shipment |
|---------------|---------|--------------------|
| STBV45 | BV45 | TO-92 / Bulk |
| STBV45-AP | BV45 | TO-92 / Ammopack |

- HIGH VOLTAGE CAPABILITY
- LOW SPREAD OF DYNAMIC PARAMETERS
- MINIMUM LOT-TO-LOT SPREAD FOR RELIABLE OPERATION
- VERY HIGH SWITCHING SPEED

APPLICATIONS:

- COMPACT FLUORESCENT LAMPS (CFLS)

DESCRIPTION

The device is manufactured using High Voltage Multi Epitaxial Planar technology for high switching speeds and high voltage capability.

It uses a Cellular Emitter structure with planar edge termination to enhance switching speeds while maintaining the wide RBSOA.

The STBV series is designed for use in Compact Fluorescent Lamps.

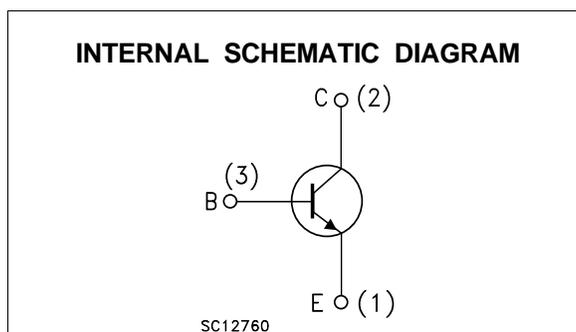
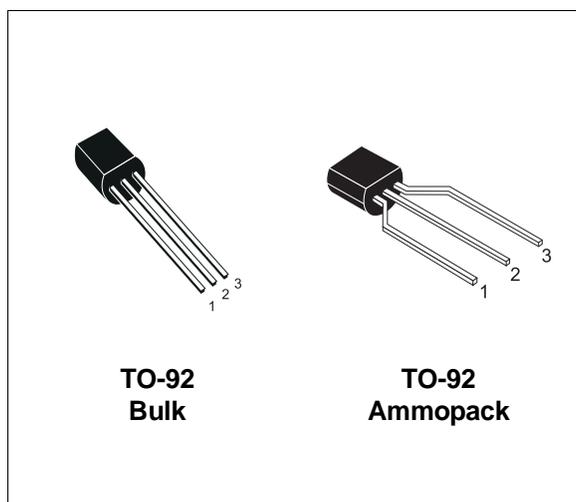


Table 2: Absolute Maximum Ratings

| Symbol | Parameter | Value | Unit |
|-----------|--|------------|------|
| V_{CES} | Collector-Emitter Voltage ($V_{BE} = 0$) | 700 | V |
| V_{CEO} | Collector-Emitter Voltage ($I_B = 0$) | 400 | V |
| V_{EBO} | Emitter-Base Voltage ($I_C = 0$) | 9 | V |
| I_C | Collector Current | 0.75 | A |
| I_{CM} | Collector Peak Current ($t_p < 5$ ms) | 1.5 | A |
| I_B | Base Current | 0.4 | A |
| I_{BM} | Base Peak Current ($t_p < 5$ ms) | 0.75 | A |
| P_{tot} | Total Dissipation at $T_{amb} = 25$ °C | 0.95 | W |
| T_{stg} | Storage Temperature | -65 to 150 | °C |
| T_j | Max. Operating Junction Temperature | 150 | °C |

Rev. 2

Table 3: Thermal Data

| | | | | |
|---------------|-------------------------------------|-----|-------|------|
| $R_{thj-amb}$ | Thermal Resistance Junction-ambient | Max | 131.6 | °C/W |
|---------------|-------------------------------------|-----|-------|------|

Table 4: Electrical Characteristics ($T_{case} = 25\text{ °C}$ unless otherwise specified)

| Symbol | Parameter | Test Conditions | | Min. | Typ. | Max. | Unit |
|-----------------|--|---|---|---------|-------------------|-----------------|-------------|
| I_{CEV} | Collector Cut-off Current ($V_{BE} = -1.5V$) | $V_{CE} = 700\text{ V}$ | | | | 250 | μA |
| I_{EBO} | Emitter Cut-off Current ($I_C = 0$) | $V_{EB} = 9\text{ V}$ | | | | 1 | mA |
| $V_{CEO(sus)*}$ | Collector-Emitter Sustaining Voltage ($I_B = 0$) | $I_C = 1\text{ mA}$ | | 400 | | | V |
| $V_{CE(sat)*}$ | Collector-Emitter Saturation Voltage | $I_C = 0.2\text{ A}$ $I_C = 0.3\text{ A}$ $I_C = 0.4\text{ A}$ | $I_B = 40\text{ mA}$ $I_B = 75\text{ mA}$ $I_B = 135\text{ mA}$ | | 0.2 0.3 0.4 | 0.5 1 1.5 | V V V |
| $V_{BE(sat)*}$ | Base-Emitter Saturation Voltage | $I_C = 0.2\text{ A}$ $I_C = 0.3\text{ A}$ | $I_B = 40\text{ mA}$ $I_B = 75\text{ mA}$ | | | 1 1.2 | V V |
| h_{FE*} | DC Current Gain | $I_C = 0.2\text{ A}$ $I_C = 0.4\text{ A}$ | $V_{CE} = 5\text{ V}$ $V_{CE} = 5\text{ V}$ | 10 5 | | 30 20 | |
| t_f | INDUCTIVE LOAD Fall Time | $I_C = 0.2\text{ A}$ $I_{B1} = -I_{B2} = 40\text{ mA}$ (see figure 7) | $V_{clamp} = 300\text{ V}$ $L = 3\text{ mH}$ | | 0.3 | | μs |

* Pulsed: Pulse duration = 300 μs , duty cycle = 1.5 %

Figure 1: Safe Operating Area

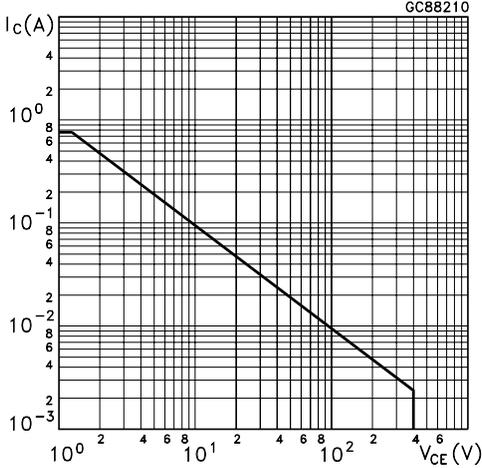


Figure 2: Derating Curve

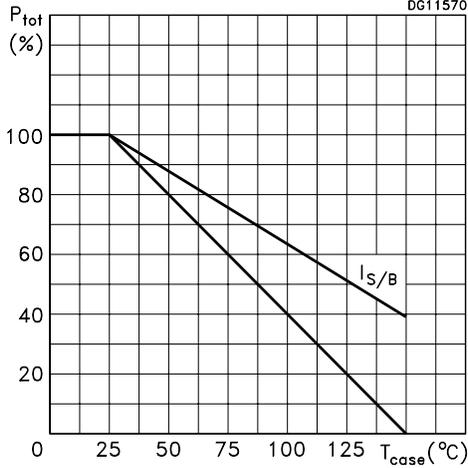


Figure 3: Collector Emitter Saturation Voltage

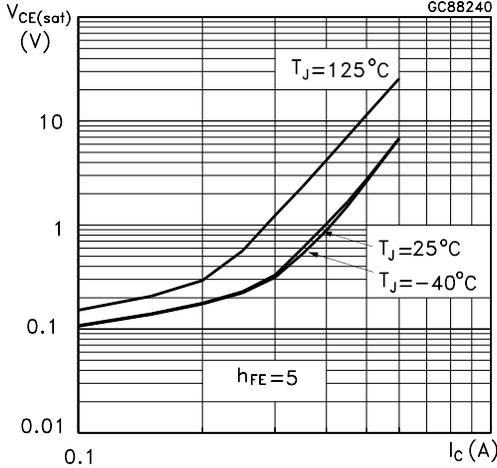


Figure 4: Base Emitter Saturation Voltage

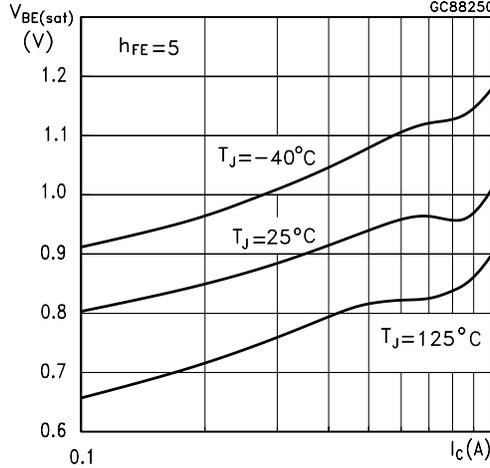


Figure 5: DC Current Gain

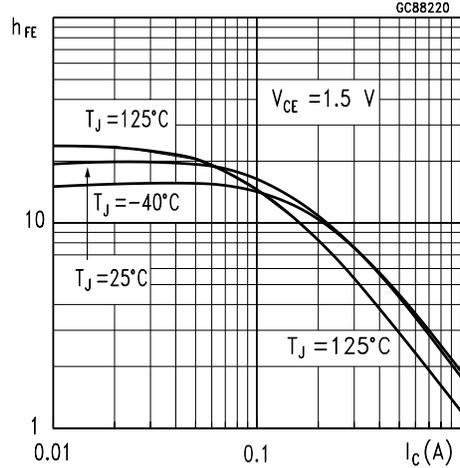


Figure 6: DC Current Gain

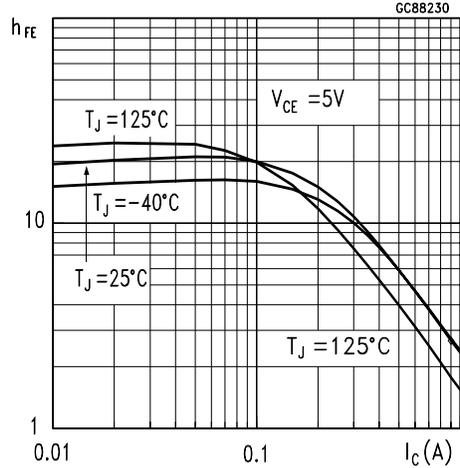
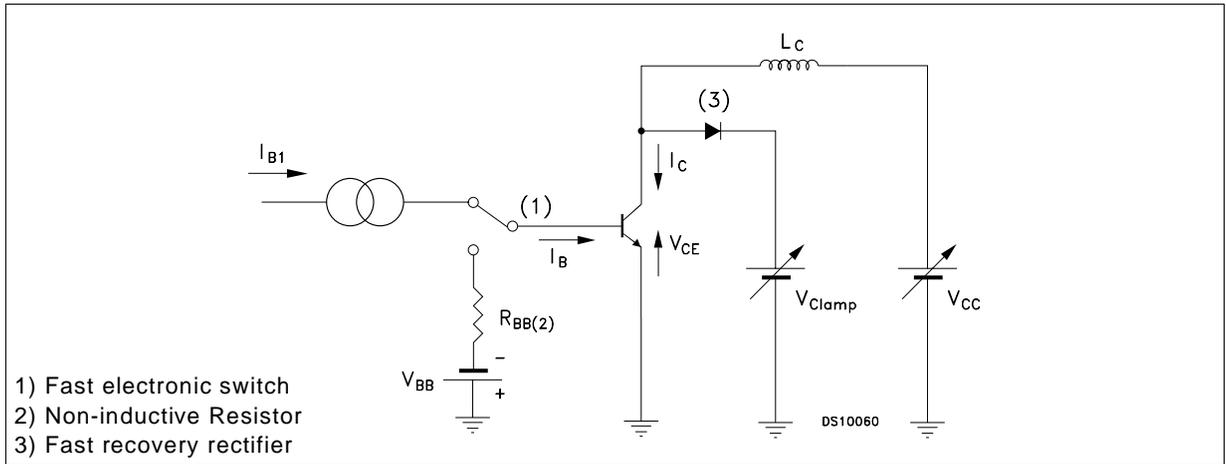
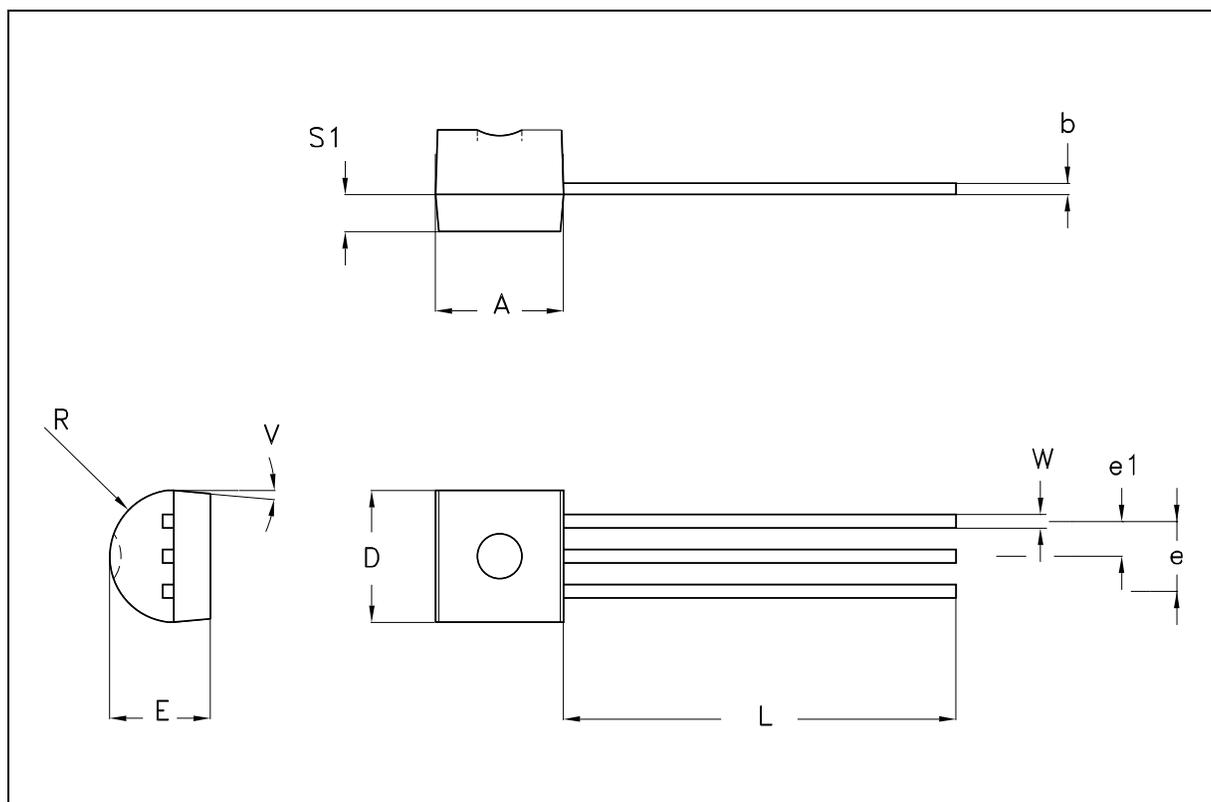


Figure 7: Inductive Load Switching Test Circuit.



TO-92 MECHANICAL DATA

| DIM. | mm | | | inch | | |
|------|----------|------|----------|----------|------|----------|
| | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. |
| A | 4.32 | | 4.95 | 0.170 | | 0.195 |
| b | 0.36 | | 0.51 | 0.014 | | 0.020 |
| D | 4.45 | | 4.95 | 0.175 | | 0.194 |
| E | 3.30 | | 3.94 | 0.130 | | 0.155 |
| e | 2.41 | | 2.67 | 0.095 | | 0.105 |
| e1 | 1.14 | | 1.40 | 0.045 | | 0.055 |
| L | 12.70 | | 15.49 | 0.500 | | 0.609 |
| R | 2.16 | | 2.41 | 0.085 | | 0.094 |
| S1 | 1.14 | | 1.52 | 0.045 | | 0.059 |
| W | 0.41 | | 0.56 | 0.016 | | 0.022 |
| V | 4 degree | | 6 degree | 4 degree | | 6 degree |



TO-92 AMMOPACK SHIPMENT (Suffix"-AP") MECHANICAL DATA

| DIM. | mm | | | inch | | |
|---------|-------|-------|-------|--------|-------|-------|
| | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. |
| A1 | | | 4.80 | | | 0.189 |
| T | | | 3.80 | | | 0.150 |
| T1 | | | 1.60 | | | 0.063 |
| T2 | | | 2.30 | | | 0.091 |
| d | | | 0.48 | | | 0.019 |
| P0 | 12.50 | 12.70 | 12.90 | 0.492 | 0.500 | 0.508 |
| P2 | 5.65 | 6.35 | 7.05 | 0.222 | 0.250 | 0.278 |
| F1,F2 | 2.44 | 2.54 | 2.94 | 0.096 | 0.100 | 0.116 |
| delta H | -2.00 | | 2.00 | -0.079 | | 0.079 |
| W | 17.50 | 18.00 | 19.00 | 0.689 | 0.709 | 0.748 |
| W0 | 5.70 | 6.00 | 6.30 | 0.224 | 0.236 | 0.248 |
| W1 | 8.50 | 9.00 | 9.25 | 0.335 | 0.354 | 0.364 |
| W2 | | | 0.50 | | | 0.020 |
| H | 18.50 | | 20.50 | 0.728 | | 0.807 |
| H0 | 15.50 | 16.00 | 16.50 | 0.610 | 0.630 | 0.650 |
| H1 | | | 25.00 | | | 0.984 |
| D0 | 3.80 | 4.00 | 4.20 | 0.150 | 0.157 | 0.165 |
| t | | | 0.90 | | | 0.035 |
| L | | | 11.00 | | | 0.433 |
| l1 | 3.00 | | | 0.118 | | |
| delta P | -1.00 | | 1.00 | -0.039 | | 0.039 |

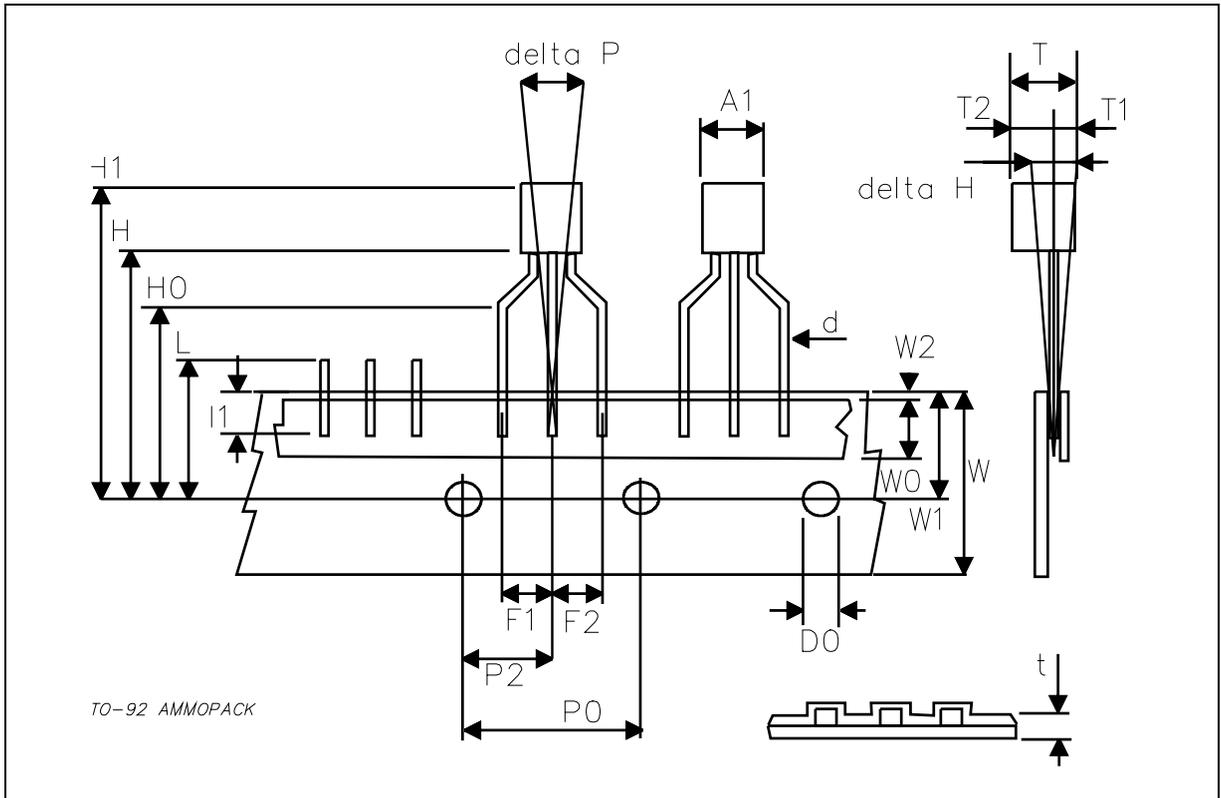


Table 5: Revision History

| Date | Revision | Description of Changes |
|-------------|----------|---|
| 6 July 2004 | 2 | Updated the V_{CE} Maximum Rating value from 600V to 700V |

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